

- State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$
- I_{off} and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model ($C = 200$ pF, $R = 0$)
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Ceramic (J) DIPs

description

These octal buffers and line drivers are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices are organized as two 4-bit buffer/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the devices pass data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

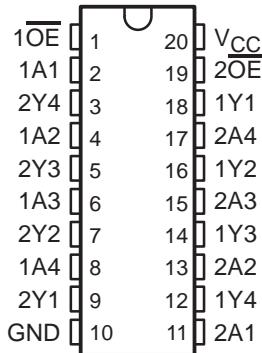
Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

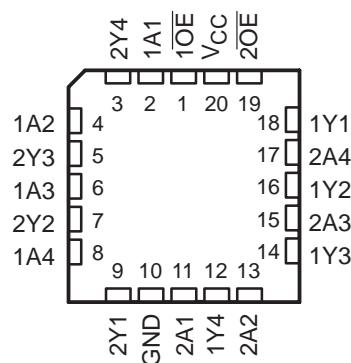
These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN54LVTH240 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74LVTH240 is characterized for operation from -40°C to 85°C .

SN54LVTH240 . . . J PACKAGE
SN74LVTH240 . . . DB, DW, OR PW PACKAGE
(TOP VIEW)



SN54LVTH240 . . . FK PACKAGE
(TOP VIEW)



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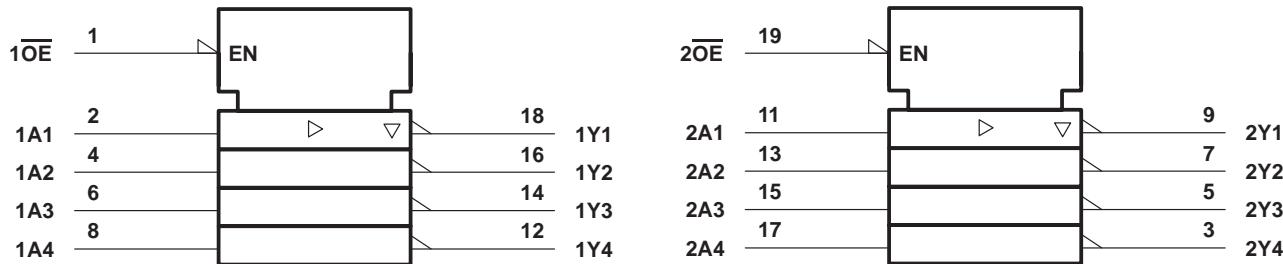
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FUNCTION TABLE
 (each buffer)

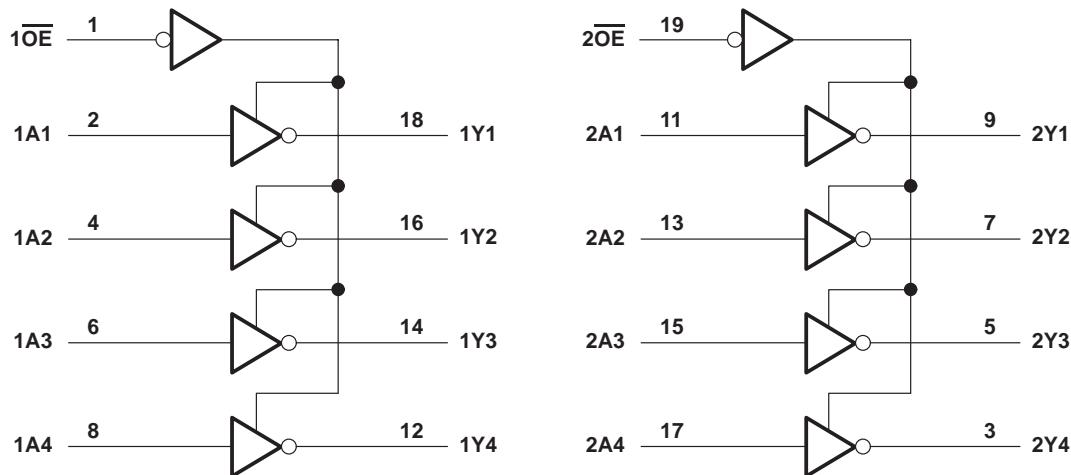
INPUTS		OUTPUT
\overline{OE}	A	Y
L	H	L
L	L	H
H	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

		SN54LVTH240		SN74LVTH240		UNIT
		MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage	2.7	3.6	2.7	3.6	V
V _{IH}	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
V _I	Input voltage		5.5		5.5	V
I _{OH}	High-level output current		-24		-32	mA
I _{OL}	Low-level output current		48		64	mA
Δt/Δv	Input transition rise or fall rate	Outputs enabled		10	10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200		200	μs/V
T _A	Operating free-air temperature	-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	SN54LVTH240			SN74LVTH240			UNIT
		MIN	TYP†	MAX	MIN	TYP†	MAX	
V _{IK}	V _{CC} = 2.7 V, I _I = -18 mA			-1.2			-1.2	V
V _{OH}	V _{CC} = 2.7 V to 3.6 V, I _{OH} = -100 μ A	V _{CC} -0.2			V _{CC} -0.2			V
	V _{CC} = 2.7 V, I _{OH} = -8 mA	2.4			2.4			
	V _{CC} = 3 V	I _{OH} = -24 mA	2				2	
		I _{OH} = -32 mA						
V _{OL}	V _{CC} = 2.7 V	I _{OL} = 100 μ A		0.2		0.2		V
		I _{OL} = 24 mA		0.5		0.5		
	V _{CC} = 3 V	I _{OL} = 16 mA		0.4		0.4		
		I _{OL} = 32 mA		0.5		0.5		
		I _{OL} = 48 mA		0.55				
		I _{OL} = 64 mA				0.55		
I _I	V _{CC} = 0 or 3.6 V, V _I = 5.5 V			10		10		μ A
	Control inputs	V _{CC} = 3.6 V, V _I = V _{CC} or GND		\pm 1		\pm 1		
	Data inputs	V _{CC} = 3.6 V	V _I = V _{CC}	1		1		
			V _I = 0		-5		-5	
I _{off}	V _{CC} = 0, V _I or V _O = 0 to 4.5 V					\pm 100		μ A
I _{I(hold)}	Data inputs	V _{CC} = 3 V	V _I = 0.8 V	75		75		μ A
			V _I = 2 V	-75		-75		
		V _{CC} = 3.6 V‡	V _I = 0 to 3.6 V			500	-750	
I _{OZH}	V _{CC} = 3.6 V, V _O = 3 V			5		5		μ A
I _{OZL}	V _{CC} = 3.6 V, V _O = 0.5 V			-5		-5		μ A
I _{OZPU}	V _{CC} = 0 to 1.5 V, V _O = 0.5 V to 3 V, OE = don't care			\pm 100*		\pm 100		μ A
I _{OZPD}	V _{CC} = 1.5 V to 0, V _O = 0.5 V to 3 V, OE = don't care			\pm 100*		\pm 100		μ A
I _{CC}	V _{CC} = 3.6 V, I _O = 0, V _I = V _{CC} or GND	Outputs high		0.19		0.19		mA
		Outputs low		5		5		
		Outputs disabled		0.19		0.19		
Δ I _{CC} §	V _{CC} = 3 V to 3.6 V, One input at V _{CC} - 0.6 V, Other inputs at V _{CC} or GND			0.2		0.2		mA
C _i	V _I = 3 V or 0			3		3		pF
C _o	V _O = 3 V or 0			7		7		pF

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

‡ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

§ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

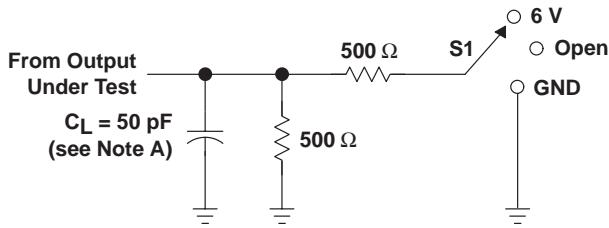
PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVTH240				SN74LVTH240				UNIT
			V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX
t _{PLH}	A	Y	0.9	4.3		5.1	1.1	2.2	3.8		4.6
t _{PHL}			1.2	4.7		4.9	1.3	2.6	4		4.2
t _{PZH}	$\overline{\text{OE}}$	Y	1	5.7		6.7	1.1	2.6	4.6		5.6
t _{PZL}			1.2	5.5		6.2	1.4	2.7	4.4		5
t _{PHZ}	$\overline{\text{OE}}$	Y	1	5.1		5.2	2	2.9	4.4		4.6
t _{PLZ}			1.1	5.4		5.4	1.8	3	4.3		4.3

† All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^\circ\text{C}$.

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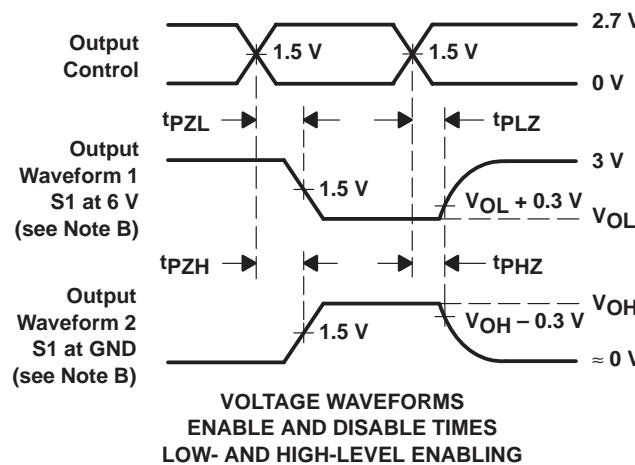
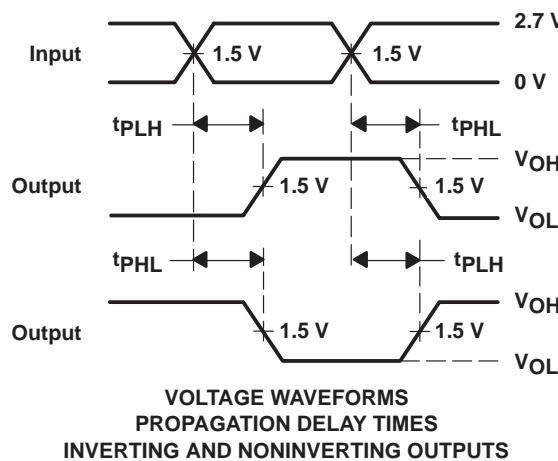
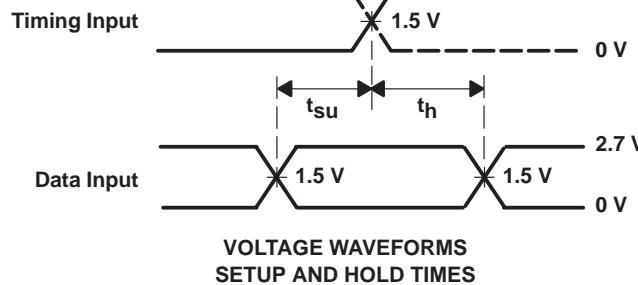
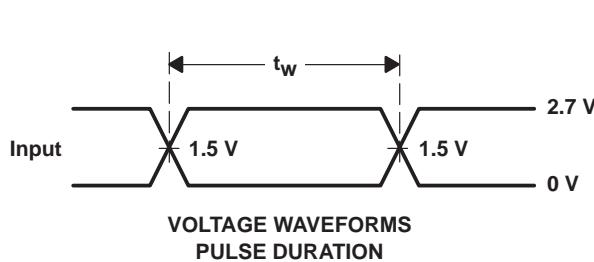
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PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.
 D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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